NSN 5961-00-405-8873

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-405-8873 **Inclosure Material:** Glass **Overall Length:** Between 0.120 inches and 0.200 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.060 inches and 0.090 inches **Function For Which Designed:** Switching **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.25 forward voltage, total rms **Current Rating Per Characteristic:** 4.00 amperes source cutoff current absolute **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** 5.0 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 18338-111516 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: